

# Rectifier Module for Power Factor Correction

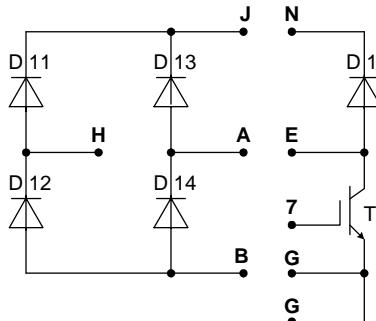
Fast Single Phase Rectifier  
Ultra Fast Boost Chopper

**V<sub>RRM</sub> = 1200 V**

**I<sub>FAV25</sub> = 15 A**

**V<sub>CES</sub> = 600 V**

**I<sub>C25</sub> = 37 A**



## Typical Rectified Mains Power

**P<sub>n</sub> = 900 W** at V<sub>n</sub> = 110 V

**P<sub>n</sub> = 2100 W** at V<sub>n</sub> = 240 V

at V<sub>DC</sub> = 400 V, f<sub>T</sub> = 75 kHz, T<sub>C</sub> = 80°C

## Input Rectifier Bridge D11 - D14

Symbol	Conditions	Maximum Ratings		
V <sub>RRM</sub>		1200	V	
I <sub>FAV25</sub>	T <sub>C</sub> = 25°C; sine 180°	15	A	
I <sub>FAV80</sub>	T <sub>C</sub> = 80°C; sine 180°	10	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 25°C; t = 10 ms sine 50 Hz	75	A	

## Symbol Conditions

## Characteristic Values

(T<sub>VJ</sub> = 25°C, unless otherwise specified)

min. typ. max.

V <sub>F</sub>	I <sub>F</sub> = 10 A	T <sub>VJ</sub> = 25°C	1.4	1.8	V
		T <sub>VJ</sub> = 125°C	1.6		V
I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub>	T <sub>VJ</sub> = 25°C	0.05	0.5	mA
		T <sub>VJ</sub> = 125°C			mA
t <sub>rr</sub>	V <sub>R</sub> = 100 V; I <sub>F</sub> = 10 A; -di/dt = 5 A/μs		1		μs
R <sub>thJC</sub>	(per diode)		tbd	2.5	K/W
		with heat transfer paste			K/W

## Application

- single phase rectification with power factor correction (PFC)
- low harmonic content of mains current
- mains current and voltage in phase
- wide input voltage range, controlled output voltage

## Features

- high level of integration - only one power semiconductor module required for the whole PFC rectifier
- standard PFC control ICs useable
- fast rectifier diodes for enhanced EMC behaviour
- NPT IGBT with low saturation voltage, ultra fast switching capability, high RBSOA and short circuit ruggedness
- internally **series connected** HiPerFRED™ free wheeling diode for fast and soft reverse recovery at high switching frequency
- package with insulated DCB base and soldering pins for PCB mounting

**Chopper T**

<b>Symbol</b>	<b>Conditions</b>	<b>Maximum Ratings</b>		
$V_{CES}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$	600		V
$V_{GES}$	Continous	$\pm 20$		V
$I_{C25}$	$T_C = 25^\circ\text{C}$	37		A
$I_{C80}$	$T_C = 80^\circ\text{C}$	25		A
<b>RBSOA</b>	$V_{CE} = 600 \text{ V}$ ; $R_G = 10 \Omega$ ; $T_{VJ} = 125^\circ\text{C}$ Clamped inductive load; $L = 100 \mu\text{H}$	$I_{CM} = 100$ $V_{CEK} \leq V_{CES}$		A
$t_{sc}$	$V_{CE} = 600 \text{ V}$ ; $V_{GE} = \pm 15 \text{ V}$ ; $R_G = 10 \Omega$ ; $T_{VJ} = 125^\circ\text{C}$ ; non-repetitive	10	$\mu\text{s}$	

<b>Symbol</b>	<b>Conditions</b>	<b>Characteristic Values</b>		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		<b>min.</b>	<b>typ.</b>	<b>max.</b>
$V_{CE(sat)}$	$I_C = 10 \text{ A}$ ; $V_{GE} = 15 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	1.5 1.6	1.8	V
$V_{GE(th)}$	$I_C = 1 \text{ mA}$ ; $V_{GE} = V_{CE}$	3	5	V
$I_{CES}$	$V_{CE} = V_{CES}$ ; $V_{GE} = 0 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		0.04	mA
$I_{GES}$	$V_{CE} = 0 \text{ V}$ ; $V_{GE} = \pm 20 \text{ V}$		100	nA
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $E_{on}$ $E_{off}$	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 400 \text{ V}$ ; $I_C = 10 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$ ; $R_G = 10 \Omega$	30 50 320 70 0.60 0.31	ns ns ns ns mJ mJ	
$C_{ies}$ $Q_{Gon}$	$V_{CE} = 25 \text{ V}$ ; $V_{GE} = 0 \text{ V}$ ; $f = 1 \text{ MHz}$ $V_{CE} = 480 \text{ V}$ ; $V_{GE} = 15 \text{ V}$ ; $I_C = 10 \text{ A}$	1600 140		pF nC
$R_{thJC}$ $R_{thJS}$	with heat transfer paste	tbd	0.96	K/W
				K/W

**Chopper D1**

<b>Symbol</b>	<b>Conditions</b>	<b>Maximum Ratings</b>		
$V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$	600		V
$I_{F25}$	$T_C = 25^\circ\text{C}$	35		A
$I_{F80}$	$T_C = 80^\circ\text{C}$	22		A
<b>Symbol</b>	<b>Conditions</b>	<b>Characteristic Values</b>		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		<b>min.</b>	<b>typ.</b>	<b>max.</b>
$V_F$	$I_F = 10 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	2.2 2.4	3.2 V	V
$I_R$	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	0.1	0.1	mA
$I_{RM}$ $t_{rr}$	$I_F = 10 \text{ A}$ ; $di_F/dt = -400 \text{ A}/\mu\text{s}$ ; $T_{VJ} = 125^\circ\text{C}$ $V_R = 400 \text{ V}$	tbd tbd		A ns
$R_{thJC}$ $R_{thJS}$	with heat transfer paste	tbd	1.15	K/W
				K/W

**Module**

<b>Symbol</b>	<b>Conditions</b>	<b>Maximum Ratings</b>		
$T_{VJ}$		-40...+150		°C
$T_{stg}$		-40...+125		°C
$V_{ISOL}$	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}; t = 1 \text{ min}$	3000	V~	
$M_d$	Mounting torque (M4)	1.5 - 2.0	Nm	

<b>Symbol</b>	<b>Conditions</b>	<b>Characteristic Values</b>		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		<b>min.</b>	<b>typ.</b>	<b>max.</b>
$d_s$	Creepage distance on surface	tbd		mm
$d_A$	Strike distance through air	tbd		mm
<b>Weight</b>	typ.	18		g

**Dimensions in mm (1 mm = 0.0394")**

